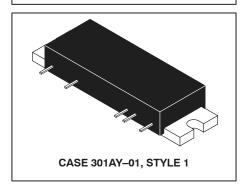
The RF Line PCS Band RF Linear LDMOS Amplifier

Designed for ultra-linear amplifier applications in 50 ohm systems operating in the PCS frequency band. A silicon FET Class A design provides outstanding linearity and gain. In addition, the excellent group delay and phase linearity characteristics are ideal for digital modulation systems, such as TDMA and CDMA.

- Third Order Intercept: 49.5 dBm Typ
- Power Gain: 29 dB Typ (@ f = 1960 MHz)
- Excellent Phase Linearity and Group Delay Characteristics
- Ideal for Feedforward Base Station Applications

MHL19936

1900–2000 MHz 12 W, 29 dB RF LINEAR LDMOS AMPLIFIER



ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
DC Supply Voltage	V_{DD}	30	Vdc
RF Input Power	P _{in}	+16	dBm
Storage Temperature Range	T _{stg}	-40 to +100	°C
Operating Case Temperature Range	T _C	-20 to +100	°C

ELECTRICAL CHARACTERISTICS ($V_{DD} = 26 \text{ Vdc}$, $T_C = 25^{\circ}\text{C}$; 50 Ω System)

Character	Symbol	Min	Тур	Max	Unit	
Supply Current		I _{DD}		1.4	1.45	А
Power Gain	(f = 1960 MHz)	Gp	28	29	30	dB
Gain Flatness	(f = 1900–2000 MHz)	G _F		0.2	0.4	dB
Power Output @ 1 dB Comp.	(f = 1950 MHz)	P1dB	40	41	_	dBm
Input VSWR	(f = 1900–2000 MHz)	VSWR _{in}		1.2:1	1.5:1	
Third Order Intercept	(f1 = 1950 MHz, f2 = 1955 MHz)	ITO	49	49.5	_	dBm
Noise Figure	(f = 2000 MHz)	NF	_	4.2	4.5	dB



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TYPICAL CHARACTERISTICS

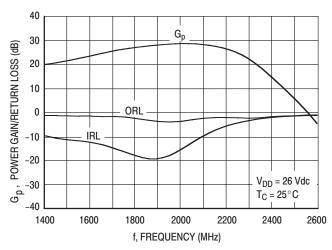


Figure 1. Power Gain, Input Return Loss, **Output Return Loss versus Frequency**

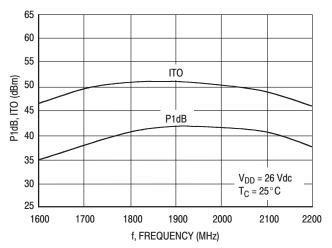


Figure 2. P1dB, ITO versus Frequency

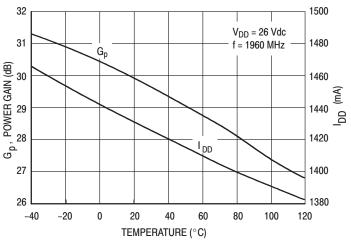


Figure 3. Power Gain, I_{DD} versus Temperature

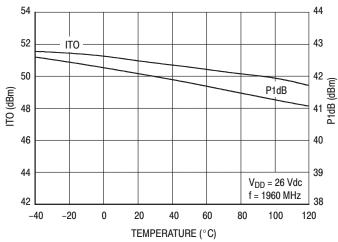


Figure 4. ITO, P1dB versus Temperature

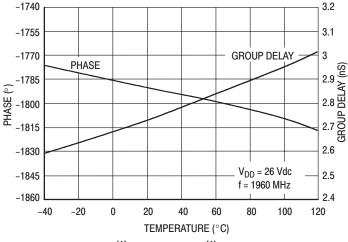


Figure 5. Phase⁽¹⁾, Group Delay⁽¹⁾ versus Temperature

(1)In Production Test Fixture

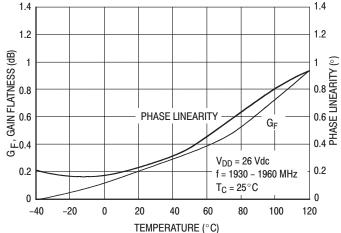


Figure 6. Gain Flatness, Phase Linearity versus Temperature

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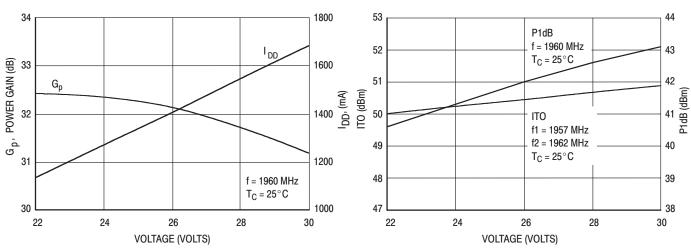


Figure 7. Power Gain, I_{DD} versus Voltage

Figure 8. ITO, P1dB versus Voltage

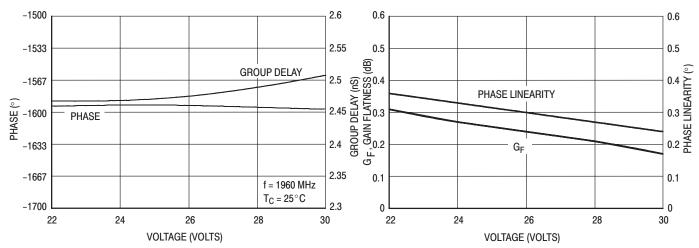


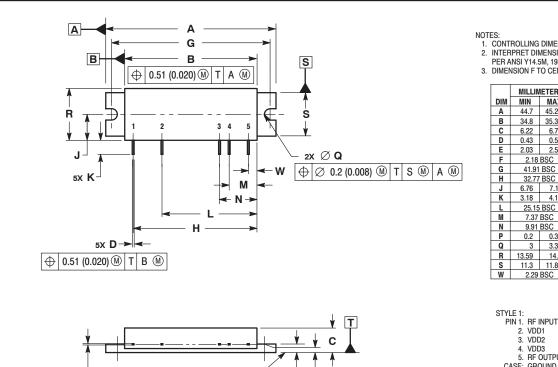
Figure 9. Phase⁽¹⁾, Group Delay⁽¹⁾ versus Voltage

(1)In Production Test Fixture

Figure 10. Phase Linearity, Gain Flatness versus Voltage

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PACKAGE DIMENSIONS



SEATING PLANE

- 1. CONTROLLING DIMENSION: MILLIMETER.
- INTERPRET DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.
- 3. DIMENSION F TO CENTER LINE OF LEADS.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	44.7	45.21	1.760	1.780	
В	34.8	35.31	1.370	1.390	
С	6.22	6.73	0.245	0.265	
D	0.43	0.58	0.017	0.023	
Е	2.03	2.54	0.080	0.100	
F	2.18	BSC	0.086 BSC		
G	41.91	BSC	1.650 BSC		
Н	32.77	BSC	1.290 BSC		
J	6.76	7.11	0.266	0.280	
K	3.18	4.19	0.125	0.165	
L	25.15	BSC	0.990 BSC		
M	7.37	BSC	0.290 BSC		
N	9.91 BSC		0.390 BSC		
P	0.2	0.33	0.008	0.013	
Q	3	3.35	0.118	0.132	
R	13.59	14.1	0.535	0.555	
S	11.3	11.81	0.445	0.465	
W	2.29 BSC		0.090 BSC		

4. VDD3 5. RF OUTPUT CASE: GROUND

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CASE 301AY-01 ISSUE O

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